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Vishay Semiconductors

Thyristor High Voltage, Phase Control SCR, 25 A



PRIMARY CHARACTERISTICS							
I _{T(AV)}	16 A						
V _{DRM} /V _{RRM}	800 V, 1200 V						
V _{TM}	1.25 V						
I _{GT}	45 mA						
T _J	-40 °C to 125 °C						
Package	3L TO-220AB						
Circuit configuration	Single SCR						

FEATURES

- Designed and qualified according to JEDEC®-JESD 47
- 125 °C max. operating junction temperature
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912



APPLICATIONS

 Typical usage is in input rectification crowbar (soft start) and AC switch in motor control, UPS, welding, and battery charge.

DESCRIPTION

The VS-25TTS... high voltage series of silicon controlled rectifiers are specifically designed for medium power switching and phase control applications. The glass passivation technology used has reliable operation up to 125 °C junction temperature.

OUTPUT CURRENT IN TYPICAL APPLICATIONS									
APPLICATIONS	ATIONS SINGLE-PHASE BRIDGE THREE-PHASE BRIDGE UNITS								
Capacitive input filter $T_A = 55 ^{\circ}\text{C}, T_J = 125 ^{\circ}\text{C}, \text{common heatsink of 1 } ^{\circ}\text{C/W}$	18	22	А						

MAJOR RATINGS AND CHARACTERISTICS									
PARAMETER	TEST CONDITIONS	VALUES	UNITS						
I _{T(AV)}	Sinusoidal waveform	16	A						
I _{RMS}		25	A						
V _{RRM} /V _{DRM}		800, 1200	V						
I _{TSM}		320	А						
V _T	16 A, T _J = 25 °C	1.25	V						
dV/dt		500	V/µs						
dl/dt		150	A/μs						
TJ		-40 to +125	°C						

VOLTAGE RATINGS									
PART NUMBER	V _{RRM} , MAXIMUM PEAK REVERSE VOLTAGE V	V _{DRM} , MAXIMUM PEAK DIRECT VOLTAGE V	I _{RRM} /I _{DRM} AT 125 °C mA						
VS-25TTS08-M3	800	800	10						
VS-25TTS12-M3	1200	1200	10						

VS-25TTS08-M3, VS-25TTS12-M3

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ABSOLUTE MAXIMUM RATINGS								
DADAMETED	OVMDOL	TF0T 00	NDITIONS	VAL	UES	LINUTO		
PARAMETER	SYMBOL	TEST CO	TYP.	UNITS				
Maximum average on-state current	I _{T(AV)}	T _C = 93 °C, 180° conduc	1	6				
Maximum RMS on-state current	I _{RMS}			2	5	Α		
Maximum peak, one-cycle,	ı	10 ms sine pulse, rated	V _{RRM} applied	2	70	^		
non-repetitive surge current	I _{TSM}	10 ms sine pulse, no vol	tage reapplied	3	20			
Maximum 12t for fusion	l ² t	10 ms sine pulse, rated	V _{RRM} applied	30	65	A ² s		
Maximum I ² t for fusing	I-I	10 ms sine pulse, no vol	515		A-S			
Maximum I ² √t for fusing	I ² √t	t = 0.1 to 10 ms, no volta	ge reapplied	51	52	A²√s		
Maximum on-state voltage drop	V_{TM}	16 A, T _J = 25 °C		1.	25	V		
On-state slope resistance	r _t	T 105 °C		12.0		mΩ		
Threshold voltage	V _{T(TO)}	- T _J = 125 °C	1.0		.0	V		
Marianora	1 /1	T _J = 25 °C	V Detective A/	0.5				
Maximum reverse and direct leakage current	I_{RM}/I_{DM}	T _J = 125 °C	V _R = Rated V _{RRM} /V _{DRM}	10				
Holding current	I _H	Anode supply = 6 V, resistive load, initial I_T = 1 A, T_J = 25 °C		-	150	mA		
Maximum latching current	ΙL	Anode supply = 6 V, resi	200					
Maximum rate of rise of off-state voltage	dV/dt	$T_J = T_J \text{ max., linear to } 80$	50	00	V/µs			
Maximum rate of rise of turned-on current	dl/dt		15	50	A/μs			

TRIGGERING						
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS		
Maximum peak gate power	P _{GM}		8.0	w		
Maximum average gate power	P _{G(AV)}		2.0	VV		
Maximum peak positive gate current	+ I _{GM}		1.5	Α		
Maximum peak negative gate voltage	- V _{GM}		10	V		
		Anode supply = 6 V, resistive load, T _J = - 10 °C	60			
Maximum required DC gate current to trigger	I_{GT}	Anode supply = 6 V, resistive load, T _J = 25 °C	45	mA		
		Anode supply = 6 V, resistive load, T _J = 125 °C	20	1		
		Anode supply = 6 V, resistive load, T _J = - 10 °C	2.5			
Maximum required DC gate voltage to trigger	V_{GT}	Anode supply = 6 V, resistive load, T _J = 25 °C	2.0	v		
voltage to trigger		Anode supply = 6 V, resistive load, T _J = 125 °C	1.0	V		
Maximum DC gate voltage not to trigger	V_{GD}	T 105 °C V Detectively	0.25			
Maximum DC gate current not to trigger	I_{GD}	T _J = 125 °C, V _{DRM} = Rated value	2.0	mA		

SWITCHING								
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS				
Typical turn-on time	t _{gt}	T _J = 25 °C	0.9					
Typical reverse recovery time	t _{rr}	T = 105 °C	4	μs				
Typical turn-off time	t _q	T _J = 125 °C	110					

THERMAL AND MECH	THERMAL AND MECHANICAL SPECIFICATIONS							
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS			
Maximum junction and storage temperature range		T_J , T_{Stg}		-40 to +125	°C			
Maximum thermal resistance, junction to case		R_{thJC}	R _{thJC} DC operation					
Maximum thermal resistance, junction to ambient		R_{thJA}		62	°C/W			
Typical thermal resistance, case to heatsink		R_{thCS}	Mounting surface, smooth and greased	0.5				
Approximate weight				2	g			
Approximate weight				0.07	oz.			
Mounting torque -	minimum			6 (5)	kgf · cm			
Wounting torque	maximum			12 (10)	(lbf · in)			
Marking davisa			Coop at do 21 TO 220AP	25TTS08				
Marking device			Case style 3L TO-220AB	25TTS12				

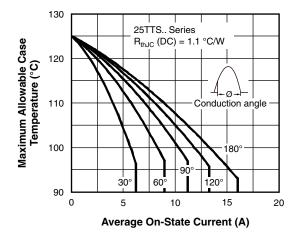


Fig. 1 - Current Rating Characteristics

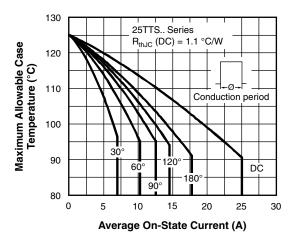


Fig. 2 - Current Rating Characteristics

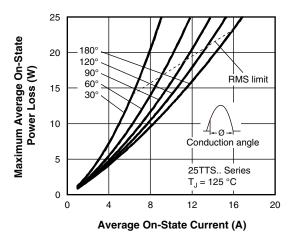


Fig. 3 - On-State Power Loss Characteristics

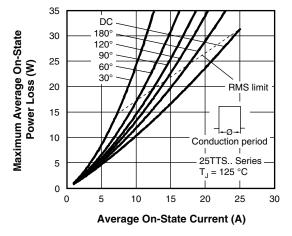
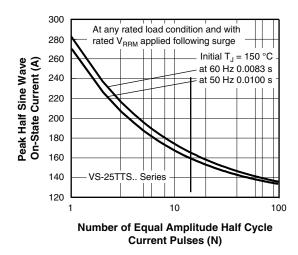


Fig. 4 - On-State Power Loss Characteristics



350 Maximum non-repetitive surge current versus pulse train duration. Control of conduction may not be maintained. 300 Peak Half Sine Wave On-State Current (A) Initial $T_J = 150 \, ^{\circ}C$ No voltage reapplied 250 Rated V_{RRM} reapplied 200 VS-25TTS. Series П 100 0.01 10 Pulse Train Duration (s)

Fig. 5 - Maximum Non-Repetitive Surge Current

Fig. 6 - Maximum Non-Repetitive Surge Current

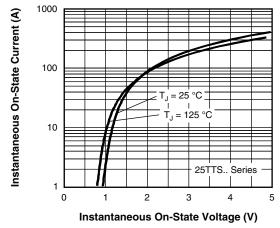


Fig. 7 - On-State Voltage Drop Characteristics

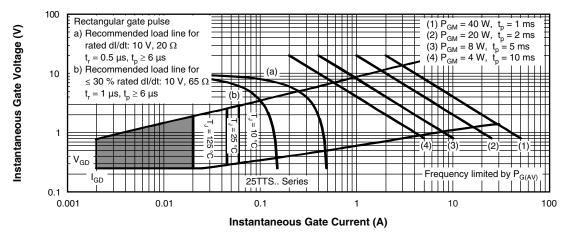


Fig. 8 - Gate Characteristics

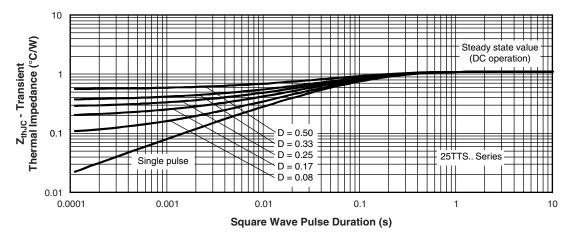
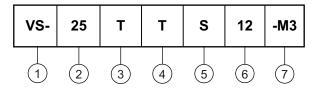


Fig. 9 - Thermal Impedance Z_{thJC} Characteristics

ORDERING INFORMATION TABLE

Device code



1 - Vishay Semiconductors product

2 - Current rating (25 = 25 A)

3 - Circuit configuration:

T = single thyristor

4 - Package:

T = TO-220AB

5 - Type of silicon:

S = standard recovery rectifier

6 - Voltage rating -- 12 = 1200 V

7 - Environmental digit:

-M3 = halogen-free, RoHS-compliant, and terminations lead (Pb)-free

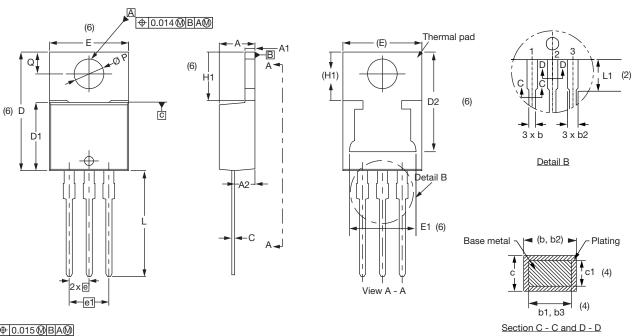
ORDERING INFORMATION (Example)									
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION						
VS-25TTS08-M3	50	1000	Antistatic plastic tubes						
VS-25TTS12-M3	50	1000	Antistatic plastic tubes						

LINKS TO RELATED DOCUMENTS							
Dimensions <u>www.vishay.com/doc?96154</u>							
Part marking information	www.vishay.com/doc?95028						

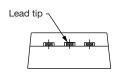


3L TO-220AB

DIMENSIONS in millimeters and inches



⊕ 0.015 **M** B A **M**



Conforms to JEDEC® outline TO-220AB

SYMBOL	MILLIM	IETERS	INC	HES	NOTES	NOTES		MILLIN	IETERS	INC	HES	NOTES
STWIBOL	MIN.	MAX.	MIN.	MAX.	NOTES		SYMBOL	MIN.	MAX.	MIN.	MAX.	NOTES
Α	4.25	4.65	0.167	0.183			D2	11.68	13.30	0.460	0.524	6, 7
A1	1.14	1.40	0.045	0.055			E	10.11	10.51	0.398	0.414	3, 6
A2	2.50	2.92	0.098	0.115			E1	6.86	8.89	0.270	0.350	6
b	0.69	1.01	0.027	0.040			е	2.41	2.67	0.095	0.105	
b1	0.38	0.97	0.015	0.038	4		e1	4.88	5.28	0.192	0.208	
b2	1.20	1.73	0.047	0.068			H1	6.09	6.48	0.240	0.255	6
b3	1.14	1.73	0.045	0.068	4		L	13.52	14.02	0.532	0.552	
С	0.36	0.61	0.014	0.024			L1	3.32	3.82	0.131	0.150	2
c1	0.36	0.56	0.014	0.022	4		ØΡ	3.54	3.91	0.139	0.154	
D	14.85	15.35	0.585	0.604	3		Q	2.60	3.00	0.102	0.118	
D1	8.38	9.02	0.330	0.355		1		•			•	

Notes

- ⁽¹⁾ Dimensioning and tolerancing as per ASME Y14.5M-1994
- (2) Lead dimension and finish uncontrolled in L1
- (3) Dimension D, D1, and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body
- (4) Dimension b1, b3, and c1 apply to base metal only
- Controlling dimensions: inches
- (6) Thermal pad contour optional within dimensions E, H1, D2, and E1
- (7) Outline conforms to JEDEC® TO-220, except D2



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